

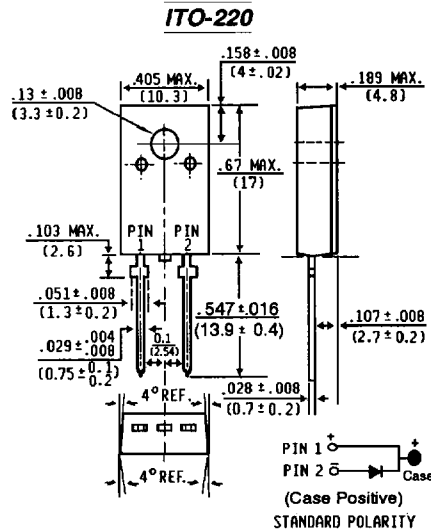
MBRF1050 AND MBRF1060

SCHOTTKY RECTIFIER

VOLTAGE RANGE - 50 and 60 Volts CURRENT - 10.0 Amperes

FEATURES

- ♦ Isolated plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- ♦ Metal to silicon rectifier, majority carrier conduction
- ♦ Low power loss, high efficiency
- ♦ High current capability, low V_F
- ♦ High surge capacity
- ♦ Epitaxial construction
- ♦ Guardring for transient protection
- ♦ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ♦ Internal Insulation: 1.5K V_{RMS}
- ♦ High temperature soldering guaranteed: 250°C/10 seconds/.25" (6.35mm) from case



Dimension in inches and (millimeters)

MECHANICAL DATA

Case: ITO-220 Fully Over Molded Plastic
Terminals: Leads Solderable per MIL-STD-750, Method 2026

Polarity: As marked

Mounting Position: Any

Mounting Torque: 5 in-lb. max.

Weight: .08 ounces, 2.24 gram

Ratings at 25°C ambient temperature unless otherwise specified.
Resistive or inductive load.

	SYMBOLS	MBRF1050	MBRF1060	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	60	Volts
Maximum Working Peak Reverse Voltage	V_{RWM}	50	60	Volts
Maximum DC Blocking Voltage	V_{DC}	50	60	Volts
Maximum Average Forward Rectified Current at $T_C=133^\circ\text{C}$	$I_{(AV)}$	10.0		Amps
Peak Repetitive Forward Current, (Square Wave 20 KHz) at $T_C=133^\circ\text{C}$	I_{FRM}	20.0		Amps
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150.0		Amps
Peak Repetitive Reverse Surge Current (NOTE 2)	I_{RRM}	0.5		Amps
Voltage Rate of Change (rated V_R)	dv/dt	1000		V/ μs
Maximum Instantaneous Forward Voltage at (NOTE 1) $I_F=1.0\text{A}, T_C=25^\circ\text{C}$ $I_F=10\text{A}, T_C=125^\circ\text{C}$ $I_F=20\text{A}, T_C=125^\circ\text{C}$ $I_F=20\text{A}, T_C=25^\circ\text{C}$	V_F	0.80 0.70 0.85 0.95		Volts
Maximum Instantaneous Reverse Current at Rated DC Block Voltage (NOTE 1) $T_C=125^\circ\text{C}$ $T_C=25^\circ\text{C}$	I_R	50.0 0.15		 mA mA
Typical Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.2		$^\circ\text{C}/\text{W}$
Operating Junction Temperature Range	T_J	-65 to +150		$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +175		$^\circ\text{C}$

NOTES: 1. Pulse Test Pulse Width 300 μs , Duty Cycle 2%.
2. 2.0 μs Pulse Width, $f=1.0\text{ KHz}$.

RATINGS AND CHARACTERISTIC CURVES MBRF1050 AND MBRF1060

FIG. 1—FORWARD CURRENT DERATING CURVE

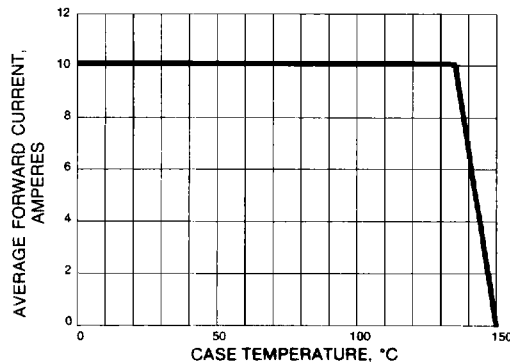


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

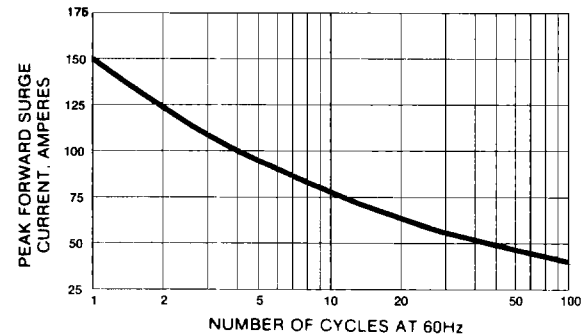


FIG. 2-TYPICAL REVERSE CHARACTERISTICS

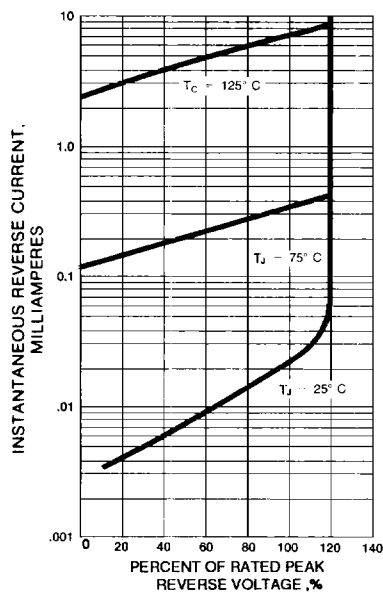


FIG. 4—TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

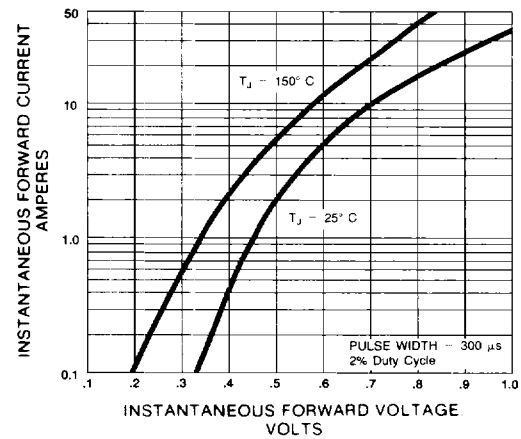


FIG. 5—TYPICAL JUNCTION CAPACITANCE

